AMENDMENT UNDER 37 C.F.R. § 1.111

Application No.: 10/053,585

AMENDMENTS TO THE CLAIMS

This listing of claims will replace all prior versions and listings of claims in the

Attorney Docket No.: Q66584

application:

LISTING OF CLAIMS:

1. (original): A surface plasmon resonance measuring chip for use in a surface

plasmon resonance measurement apparatus constituted of a light source for emitting a light

beam; an optical system for making said light beam enter a dielectric block at various angles of

incidence so that a condition for total internal reflection is satisfied at an interface between said

dielectric block and said metal film; and photodetection means for detecting the intensity of said

light beam satisfying total internal reflection at said interface to detect surface plasmon

resonance; comprising:

a dielectric block;

a metal film, formed on a surface of said dielectric block, for placing a sample thereon;

wherein said dielectric block is formed as a single block that includes an entrance surface

which said light beam enters, an exit surface from which said light beam emerges, and a surface

on which said metal film is formed;

said metal film is united with said dielectric block; and

said dielectric block is formed from a synthetic resin in which, when said light beam is p-

polarized outside said dielectric block and then strikes said interface, the intensity of an s-

polarized component at said interface is 50% or less of the intensity of said light beam at said

interface.

2. (original): The surface plasmon resonance measuring chip as set forth in claim 1,

wherein said dielectric block is formed from a synthetic resin in which, when said light beam is

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p-polarized outside said dielectric block and then strikes said interface, the intensity of a s-polarized component at said interface is 30% or less of the intensity of said light beam at said interface.

- 3. (original): The surface plasmon resonance measuring chip as set forth in claim 1, wherein said dielectric block is formed from a synthetic resin in which, when said light beam is p-polarized outside said dielectric block and then strikes said interface, the intensity of a s-polarized component at said interface is 10% or less of the intensity of said light beam at said interface.
- 4. (original): The surface plasmon resonance measuring chip as set forth in claim 1, wherein said synthetic resin is a synthetic resin that is selected from polymethylmethacrylate, a cycloolefin polymer, or a cycloolefin copolymer.
- 5. (original): The surface plasmon resonance measuring chip as set forth in claim 2, wherein said synthetic resin is a synthetic resin that is selected from polymethylmethacrylate, a cycloolefin polymer, or a cycloolefin copolymer.
- 6. (original): The surface plasmon resonance measuring chip as set forth in claim 3, wherein said synthetic resin is a synthetic resin that is selected from polymethylmethacrylate, a cycloolefin polymer, or a cycloolefin copolymer.
- 7. (original): The surface plasmon resonance measuring chip as set forth in claim 1, wherein a sensing medium that exhibits a coupling reaction with a specific substance in said sample is fixed on said metal film.
- 8. (original): The surface plasmon resonance measuring chip as set forth in claim 2, wherein a sensing medium that exhibits a coupling reaction with a specific substance in said sample is fixed on said metal film.

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9. (original): The surface plasmon resonance measuring chip as set forth in claim 3, wherein a sensing medium that exhibits a coupling reaction with a specific substance in said sample is fixed on said metal film.

- 10. (previously presented): The surface plasmon resonance measuring chip as set forth in claim 4, wherein a sensing medium that exhibits a coupling reaction with a specific substance in said sample is fixed on said metal film.
- 11. (original): The surface plasmon resonance measuring chip as set forth in claim 4, wherein a sensing medium that exhibits a coupling reaction with a specific substance in said sample is fixed on said metal film.
- 12. (original): The surface plasmon resonance measuring chip as set forth in claim 6, wherein a sensing medium that exhibits a coupling reaction with a specific substance in said sample is fixed on said metal film.
 - 13. (canceled).
- 14. (previously presented): The surface plasmon resonance measuring chip as set forth in claim 1, wherein said sample is fixed on said metal film and is held in a sample holding frame which is integrally formed on said dielectric block.
- 15. (previously presented): The surface plasmon resonance measuring chip as set forth in claim 1, wherein a top surface of said dielectric block is contiguous to said metal film such that there is substantially no air gap between said top surface of said dielectric block and said metal film.
- 16. (previously presented): The surface plasmon resonance measuring chip as set forth in claim 1, wherein said dielectric block and said metal film are integrally formed.

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17. (previously presented): The surface plasmon resonance measuring chip as set forth in claim 1, wherein said dielectric block is formed in the shape of a rectangular parallelepiped.

- 18. (previously presented): The surface plasmon resonance measuring chip as set forth in claim 1, wherein said metal film comprises a vapor-deposited film.
- 19. (previously presented): The surface plasmon resonance measuring chip as set forth in claim 1, wherein said entrance surface is formed on a first portion of a spherical surface of said dielectric block and,

wherein said exit surface is formed on a second portion of said spherical surface of said dielectric block.

- 20. (previously presented): The surface plasmon resonance measuring chip as set forth in claim 1, wherein said dielectric block has a cut out portion in a region where said light beam does not penetrate.
 - 21. (previously presented): The surface plasmon resonance measuring chip as set forth in claim 1,

wherein said dielectric block is formed in a quadrangular pyramid shape, and

wherein said dielectric block comprises a sample holding hole having a circular cross section which gradually increases in diameter toward a top surface of said dielectric block, and

wherein a bottom surface of said dielectric block is contiguous to said metal film.

22. (new): The chip of claim 1, wherein the light source is configured to provide p-polarized light to the dielectric block.

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23. (new): The chip of claim 1, wherein said dielectric block is formed in a quadrangular pyramid shape.

- 24. (new): The chip of claim 1, wherein the dielectric block is formed of an injected resin having no weld point at the entrance face.
- 25. (new): The chip of claim 1, wherein the dielectric block is formed of an injected resin having limited dual refraction to limit the s-polarized light intensity.